

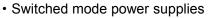
# isc N-Channel MOSFET Transistor

## IXFA30N60X

### • FEATURES

- Static drain-source on-resistance:
  R<sub>DS</sub>(on) ≤ 15 5mΩ@V<sub>GS</sub>=10V
- Fully characterized avalanche voltage and current
- 100% Avalanche Tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

### APPLICATION



• DC-DC converters

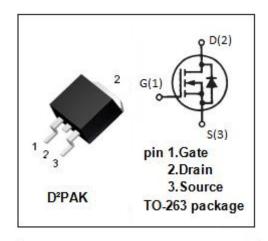


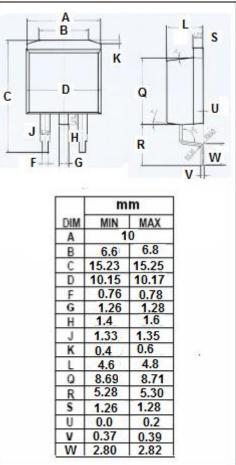
## • ABSOLUTE MAXIMUM RATINGS(T<sub>a</sub>=25°C)

SYMBOL	PARAMETER	VALUE	UNIT		
V <sub>DSS</sub>	Drain-Source Voltage	600	000 V		
V <sub>GS</sub>	Gate-Source Voltage	±30	V		
Ι <sub>D</sub>	Drain Current-Continuous 30		А		
I <sub>DM</sub>	Drain Current-Single Pulsed	60			
$P_D$	Total Dissipation @T <sub>C</sub> =25°C	ution @T <sub>C</sub> =25°C 500			
Tj	Operating Junction Temperature -55~		$^{\circ}$		
T <sub>stg</sub>	Storage Temperature	-55~150	${\mathbb C}$		

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th(j-c)</sub>	Junction-to-case thermal resistance	0.25	°C/W







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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> = 0V; ID = 1mA	600		V
V <sub>GS(th)</sub>	Gate Threshold Voltage	V <sub>DS</sub> = V <sub>GS</sub> ; ID = 4mA	2.5	4.5	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> = 15A		155	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = ±30V;V <sub>DS</sub> =0V		±100	nA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V		25	- μΑ
		V <sub>DS</sub> = V <sub>DSS</sub> ; V <sub>GS</sub> = 0V;T <sub>J</sub> = 125°C		750	
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> = 30A; V <sub>GS</sub> = 0V		1.4	V



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